650 V, 20 A high surge silicon carbide power Schottky diode

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DO-247 LL

STPOWER
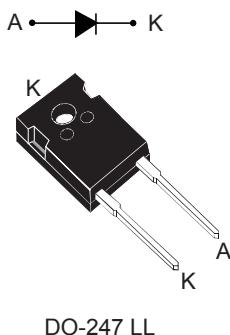
Product label
SUSTAINABLE TECHNOLOGY

Product status link
STPSC20G065

Product summary	
$I_{F(AV)}$	20 A
V_{RRM}	650 V
T_j (max.)	175 °C
V_F (typ.)	1.30 V

Features

- No reverse recovery charge in application current range
- Switching behavior independent of temperature
- High forward surge capability
- Operating T_j from -55 °C to 175 °C
- ECOPACK2 compliant component

Applications

- Solar inverter
- Air conditioning equipment
- UPS power supply
- Telecom / Server power equipment
- OBC (On board battery chargers)
- EV Charging station

Description

The SiC diode STPSC20G065, moulded in DO-247 LL with long leads, is an ultrahigh performance power Schottky rectifier. It is manufactured using a silicon carbide substrate. The wide band-gap material allows the design of a low V_F Schottky diode structure with a 650 V rating. Due to the Schottky construction, no recovery is shown at turn-off and ringing patterns are negligible. The minimal capacitive turn-off behavior is independent of temperature.

Based on latest technology optimization, this diode has an improved forward surge current capability, making it ideal for use in PFC, where this ST SiC diode boosts the performance in hard switching conditions. Using the latest design improvement of the "G" series of ST SiC diodes, as well as implemented tests in production, this diode is becoming the reference point in the combination of efficiency and application robustness to the application design.

1   Characteristics

Table 1. **Absolute ratings (limiting values at 25 °C, unless otherwise specified)**

Symbol	Parameter			Value	Unit
V_{RRM}	Repetitive peak reverse voltage (T_j = -55 °C to +175 °C)			650	V
$I_{F(RMS)}$	Forward rms current			46	A
$I_{F(AV)}$	Average forward current	T_c = 135 °C, δ = 1		20	A
I_{FRM}	Repetitive peak forward current	T_c = 135 °C, T_j = 175 °C, δ = 0.1, f_{sw} > 10 kHz		82	A
I_{FSM}	Surge non repetitive forward current	t_p = 10 ms sinusoidal	T_c = 25 °C	135	A
			T_c = 150 °C	110	
		t_p = 10 μs square	T_c = 25 °C	850	
T_{stg}	Storage temperature range			-65 to +175	°C
T_j	Operating junction temperature range			-55 to +175	°C

Table 2. **Thermal resistance parameters**

Symbol	Parameter	Value		Unit
		Typ.	Max.	
$R_{th(j-c)}$	Junction to case	0.80	1.14	°C/W

For more information, please refer to the following application note:

- AN5088 : Rectifiers thermal management, handling and mounting recommendations

Table 3. **Static electrical characteristics**

Symbol	Parameter	Test conditions		Min.	Typ.	Max.	Unit
I_R [1]	Reverse leakage current	T_j = 25 °C	V_R = V_{RRM}	-	17	200	μA
		T_j = 175 °C		-	100	800	
V_F [2]	Forward voltage drop	T_j = 25 °C	I_F = 20 A	-	1.30	1.45	V
		T_j = 175 °C		-	1.49	1.70	

1.   *Pulse test: t_p = 10 ms, δ < 2%*

2.   *Pulse test: t_p = 380 μs, δ < 2%*

To evaluate the conduction losses, use the following equation:

P = 0.879 x $I_{F(AV)}$ + 0.0405 x I_F^2 (RMS)

For more information, please refer to the following application notes related to the power losses:

- AN604: Calculation of conduction losses in a power rectifier
- AN4021: Calculation of reverse losses on a power diode

Table 4. Dynamic electrical characteristics

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
Q_{Cj} [1]	Total capacitive charge	V_R = 400 V	-	60	-	nC
C_j	Total capacitance	V_R = 0 V, T_c = 25 °C, F = 1 MHz	-	1260	-	pF
		V_R = 400 V, T_c = 25 °C, F = 1 MHz	-	83	-	

1.
$$\text{Most accurate value for the capacitive charge: } Q_{cj}(V_R) = \int_0^{V_{out}} C_j(V_R)dV_R$$

Figure 1. Thermal transient impedance model circuit of the diode – $Z_{th(j-c)}$
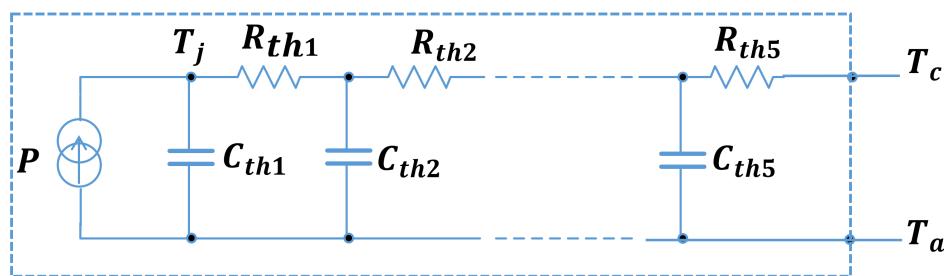
Table 5. Components typical values of the diode thermal transient impedance model $Z_{th(j-c)}$

Ref.	Value (K/W)	Ref.	Value (J/K)
R_{th1}	29.34 m	C_{th1}	1.18 m
R_{th2}	254.21 m	C_{th2}	1.09 m
R_{th3}	243.62 m	C_{th3}	6.59 m
R_{th4}	208.06 m	C_{th4}	40.71 m
R_{th5}	64.92 m	C_{th5}	484.42 m

1.1 Characteristics (curves)

Figure 2. Forward voltage drop versus forward current (typical values)

$I_F(A)$

Pulse test : t_p=380 µs

T_a=25 °C
T_a=100 °C
T_a=150 °C
T_a=175 °C

$V_F(V)$
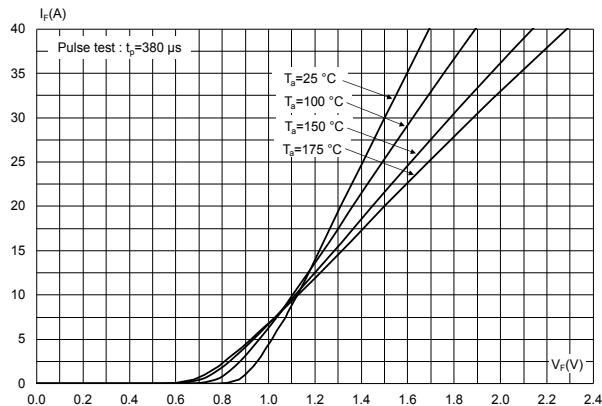
Figure 3. Reverse leakage current versus reverse voltage applied (typical values)

$I_R(µA)$

T_j=175 °C
T_j=150 °C
T_j=100 °C
T_j=25 °C

$V_R(V)$
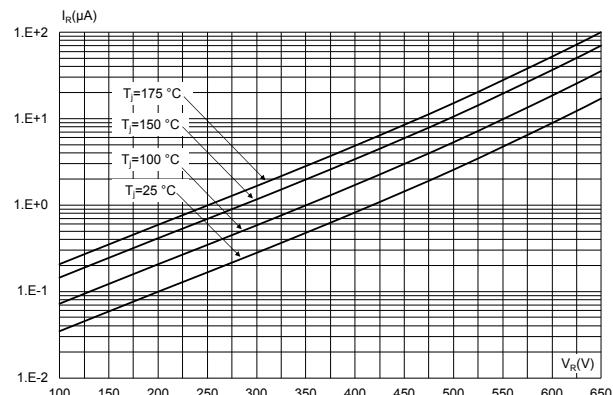
Figure 4. Peak forward current versus case temperature (f_{SW} > 10 kHz)

$I_M(A)$

δ=0.1

δ=0.3

δ=0.5

δ=1 δ=0.7

δ=tp/T

$T_C(°C)$
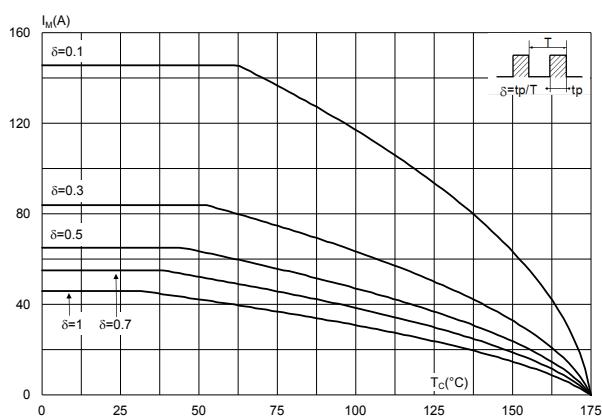
Figure 5. Junction capacitance versus reverse voltage applied (typical values)

$C_j(pF)$

F=1 MHz
V_{OSC}=30 mV_{RMS}
T_j=25 °C

$V_R(V)$
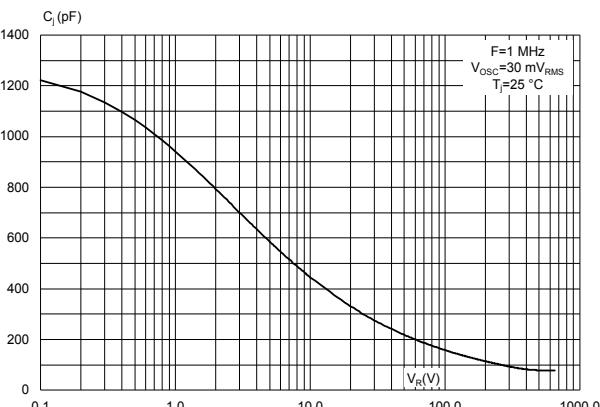
Figure 6. Relative variation of thermal impedance junction to case versus pulse duration

$Z_{th(j-c)}/R_{th(j-c)}$

Single pulse

$t_p(s)$
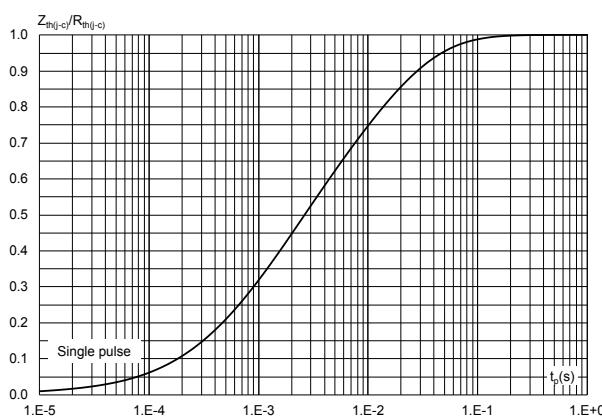
Figure 7. Non-repetitive peak surge forward current versus pulse duration (sinusoidal waveform)

$I_{FSM}(A)$

T_a=25 °C

T_a=150 °C

$t_p(s)$
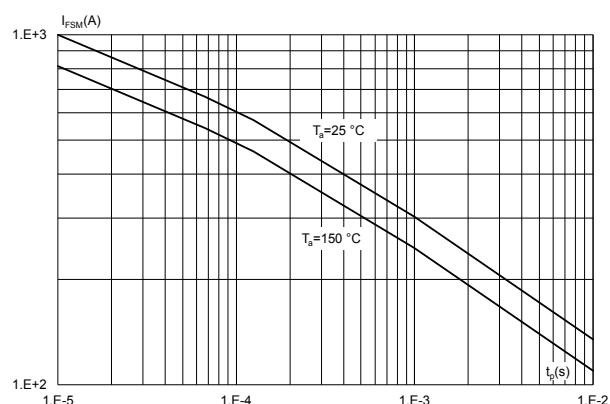
**Figure 8.** **Total capacitive charges versus reverse voltage applied (typical values)**
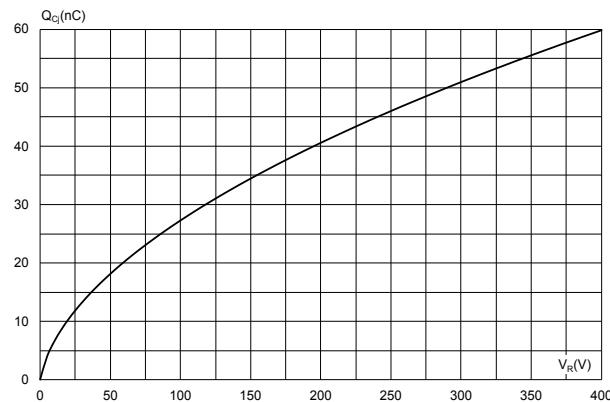
2 Package information

To meet environmental requirements, ST offers these devices in different grades of ECOPACK packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions, and product status are available at: www.st.com. ECOPACK is an ST trademark.

2.1 DO-247 LL package information

- Epoxy meets UL94, V0
- Cooling method: by conduction (C)
- Recommended torque value: 0.8 N·m
- Maximum torque value: 1.0 N·m

Figure 9. DO-247 LL package outline
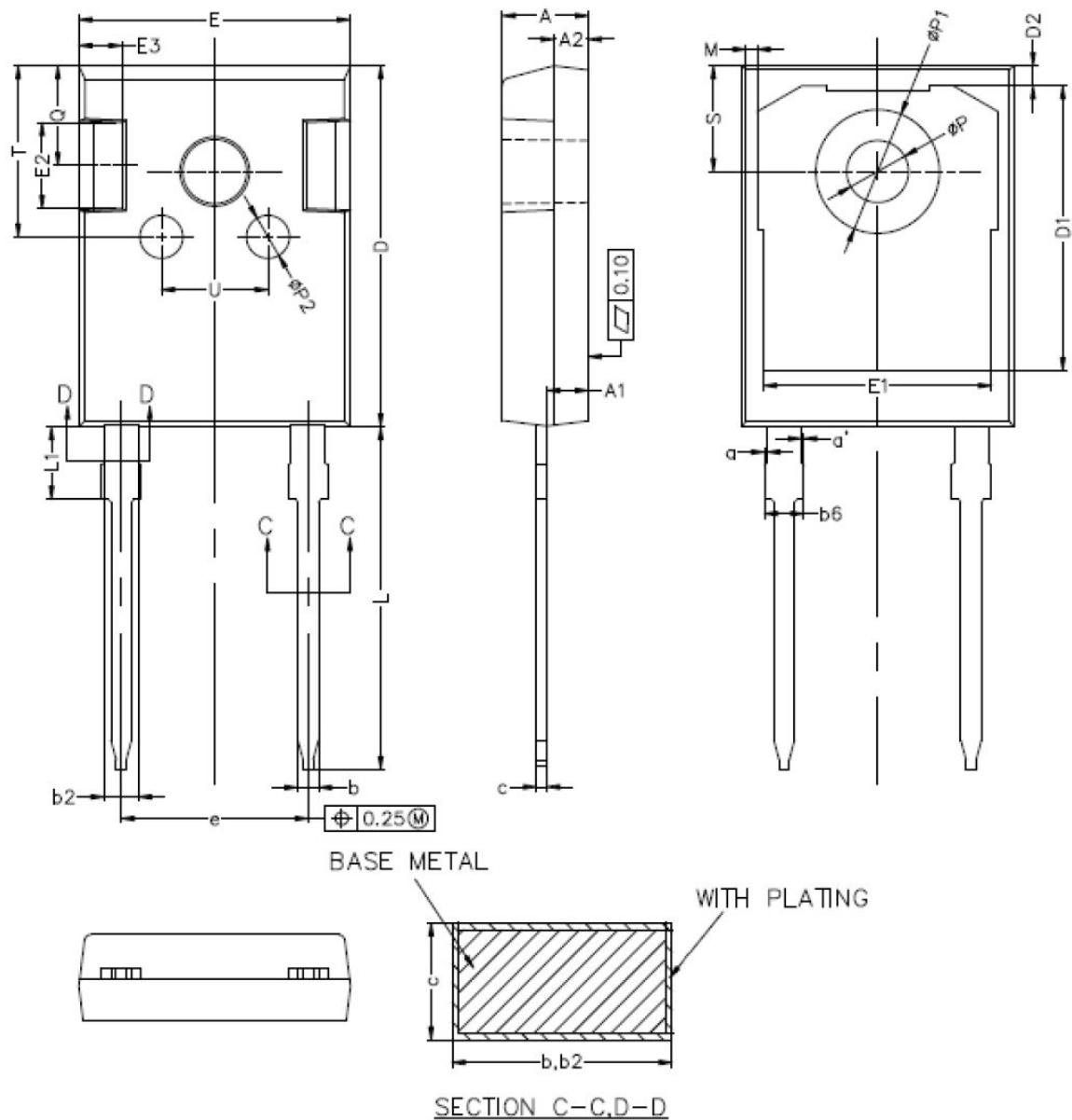
Note: This package drawing may slightly differ from the physical package. However, all the specified dimensions are guaranteed.

Table 6. DO-247 LL package mechanical data

Ref.	Dimensions					
	Millimeters			Inches (for reference only)		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	4.90	5.00	5.10	0.192	0.197	0.201
A1	2.31	2.41	2.51	0.090	0.095	0.099
A2	1.90	2.00	2.10	0.074	0.079	0.083
a	0.00		0.15	0.000		0.006
a'	0.00		0.15	0.000		0.006
b	1.16		1.29	0.045		0.051
b2	1.96		2.06	0.077		0.082
b6			2.25			0.089
c	0.59		0.66	0.023		0.026
D	20.90	21.00	21.10	0.822	0.827	0.831
D1	16.25	16.55	16.85	0.639	0.652	0.664
D2	1.05	1.20	1.35	0.041	0.047	0.054
E	15.70	15.80	15.90	0.618	0.622	0.626
E1	13.06	13.26	13.46	0.514	0.522	0.530
E2	4.90	5.00	5.10	0.192	0.197	0.201
E3	2.40	2.50	2.60	0.094	0.098	0.103
e	10.78	10.88	10.98	0.424	0.428	0.433
L	19.80	19.92	20.10	0.779	0.784	0.792
L1	3.93		4.46	0.154		0.176
M	0.35		0.95	0.013		0.038
P	3.50	3.60	3.70	0.137	0.142	0.146
P1	7.00		7.40	0.275		0.292
P2	2.40	2.50	2.60	0.094	0.098	0.103
Q	5.60		6.00	0.220		0.237
S	6.05	6.15	6.25	0.238	0.242	0.247
T	9.80		10.20	0.385		0.402
U	6.00		6.40	0.236		0.252

3 Ordering information

Table 7. Ordering information

Order code	Marking	Package	Weight	Base qty.	Delivery mode
STPSC20G065WL	SPSC20G065WL	DO-247 LL	5.9 g	30	Tube

Revision history

Table 8. Document revision history

Date	Revision	Changes
06-Dec-2024	1	Initial release.

IMPORTANT NOTICE – READ CAREFULLY